

HDMI COMPANION CHIP WITH STEP-UP DC-DC, I²C LEVEL SHIFTER, AND HIGH-SPEED ESD CLAMPS

 Check for Samples: [TPD12S015A](#)

FEATURES

- Conforms to HDMI Compliance Tests Without Any External Components
- Supports HDMI 1.4 Data Rate
- Match Class D and Class C Pin Mapping
- Excellent Matching Capacitance (0.05pF) in Each Differential Signal Pair
- Internal Boost Converter to Generate 5V From a 2.3-5.5V Battery Voltage
- Auto-direction Sensing Level Shifting in the CEC, SDA, and SCL Paths
- IEC 61000-4-2 (Level 4) System Level ESD Compliance

- Improved Drop-in Replacement for the Industry Popular TPD12S015
- Industrial Temperature Range: -40°C to 85°C

APPLICATIONS

- Smart Phones
- eBook
- Tablet PC
- Digital Camcorders
- Portable Game Console
- Digital Still Cameras

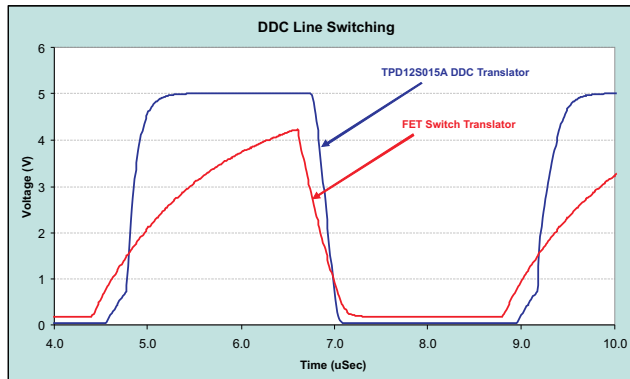
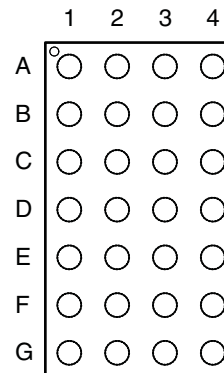


Figure 1. SCL_B or SDA_B Buffers of TPD12S015A Driving Long HDMI Cable (750pF Load)

YFF PACKAGE (TOP VIEW)



For package dimensions, see the Mechanical Drawing at the end of this document.

YFF PACKAGE PIN MAPPING

| | 1 | 2 | 3 | 4 |
|----------|------------------|------------------|-------|------|
| A | LS_OE | V _{CCA} | D2+ | D2- |
| B | SCL_A | CEC_A | GND | D1+ |
| C | SDA_A | HPD_A | GND | D1- |
| D | CT_CP_HPDP | GND | CEC_B | D0+ |
| E | FB | GND | SCL_B | D0- |
| F | 5VOUT | SW | SDA_B | CLK+ |
| G | P _{GND} | V _{BAT} | HPD_B | CLK- |



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DESCRIPTION/ORDERING INFORMATION

The TPD12S015A is an integrated HDMI companion chip solution. This device offers 8 low capacitance ESD clamps allowing HDMI 1.4 data rates. The 0.4-mm pitch WCSP package pin mapping matches the HDMI Type D or Type C connectors. The integrated ESD clamps in monolithic silicon technology provide good matching between each differential signal pair. This provides an advantage over discrete ESD clamp solutions where variations between ESD clamps degrade the differential signal quality.

The TPD12S015A provides a regulated 5V output (5VOUT) for sourcing the HDMI power line. The 5VOUT pin supplies minimum 55mA to the HDMI receiver while meeting the HDMI 5VOUT specifications. The 5VOUT and the hot plug detect (HPD) circuitry are independent of the LS_OE control signal; they are controlled by the CT_CP_HPDP pin. This independent control enables the detection scheme (5VOUT + HPD) to be active before enabling the HDMI link. The HPD_B port has a glitch filter to avoid false detection due to the bouncing while inserting the HDMI plug.

There are three non-inverting bi-directional translation circuits for the SDA, SCL, and CEC lines; they are controlled by the LS_OE control signal. Each have a common power rail (VCCA) on the A side from 1.1V to 3.6V. On the B side, the SCL_B and SDA_B each have an internal 1.75kΩ pull-up connected to the regulated 5V rail (5VOUT). The SCL and SDA pins meet the I2C specifications, and drive at least 750pF loads which exceeds the HDMI cable specification. An LDO generates a 3.3V internal rail for the CEC line operation when LS_OE = H & CT_CP_HPDP = H. The CEC_B pin has a 26kΩ pull-up to this internal 3.3V rail.

The TPD12S015A provides IEC61000-4-2 (Level 4) ESD protection. This device is offered in a space saving 1.6mm x 2.8mm WCSP package.

ORDERING INFORMATION

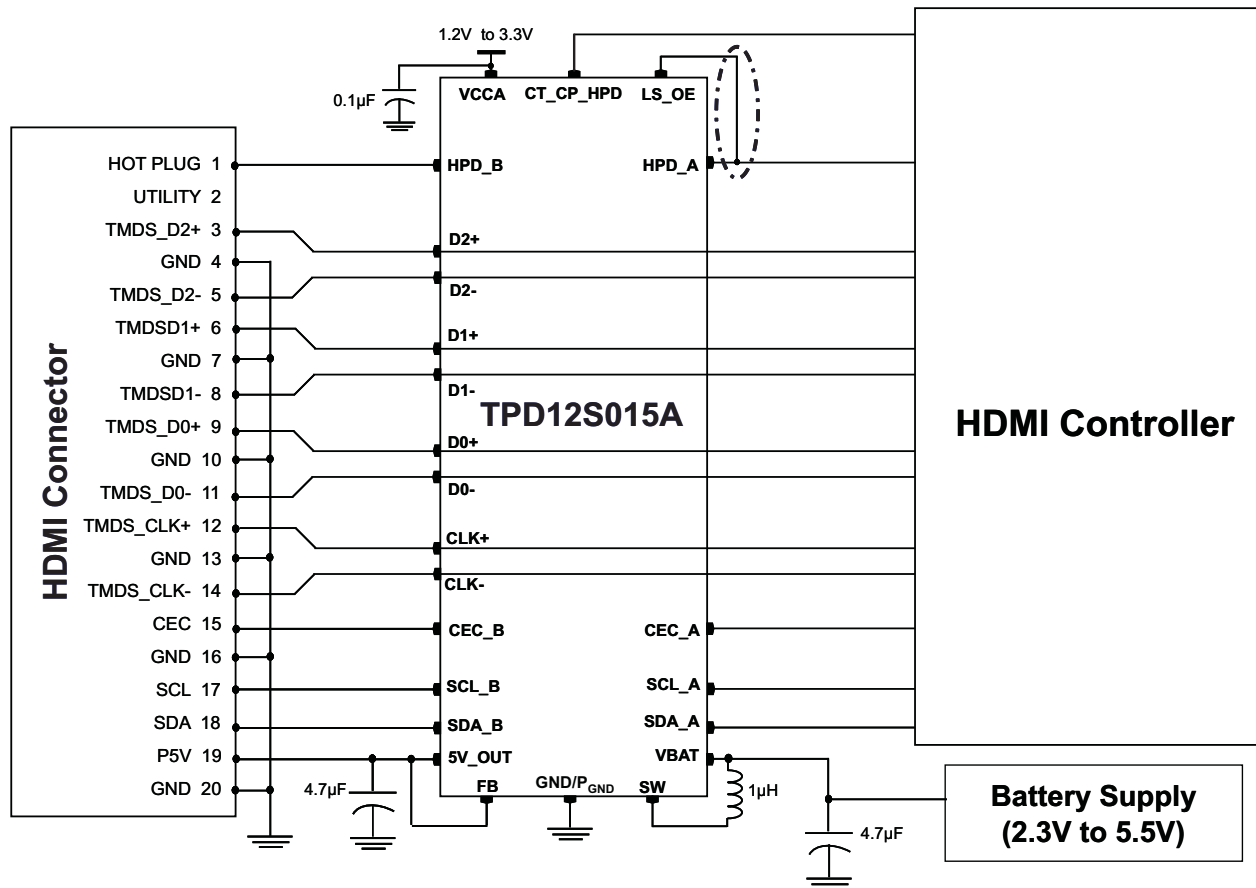
| T _A | PACKAGE ⁽¹⁾ (2) | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|----------------------------|---------------|-----------------------|------------------|
| -40°C to 85°C | WCSP – YFF | Tape and reel | TPD12S015AYFFR | PN015A |

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

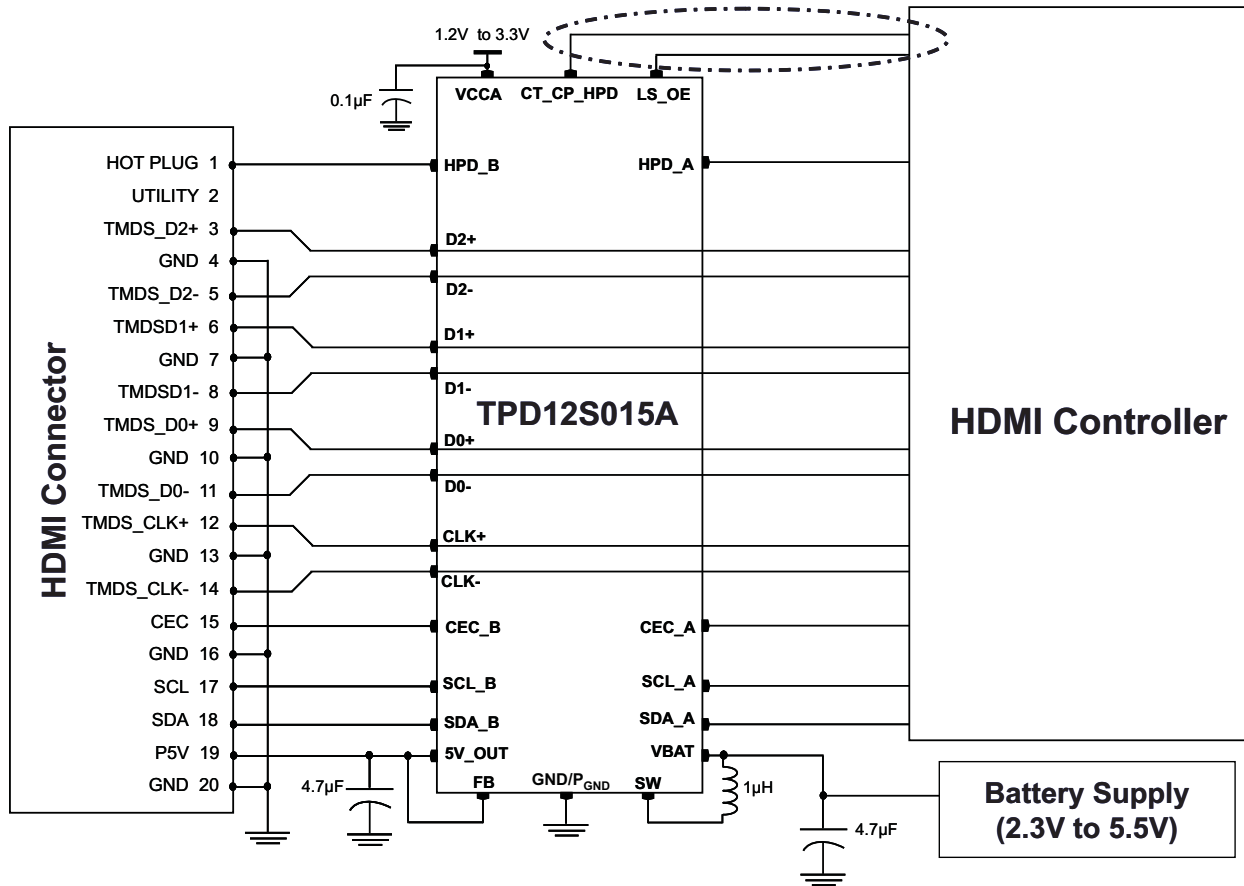
SYSTEM LEVEL BLOCK DIAGRAM

Application Schematics for HDMI controllers with one GPIO for HDMI Interface Control



Some HDMI controllers may have only one GPIO to control the HDMI interface. Refer to Figure 1, HDMI Driver Chip is controlling the TPD12S015A via only one control line (CT_CP_HPDP). In this mode the HPD_A to LS_OE pins are connected shown in the above oval dotted line.

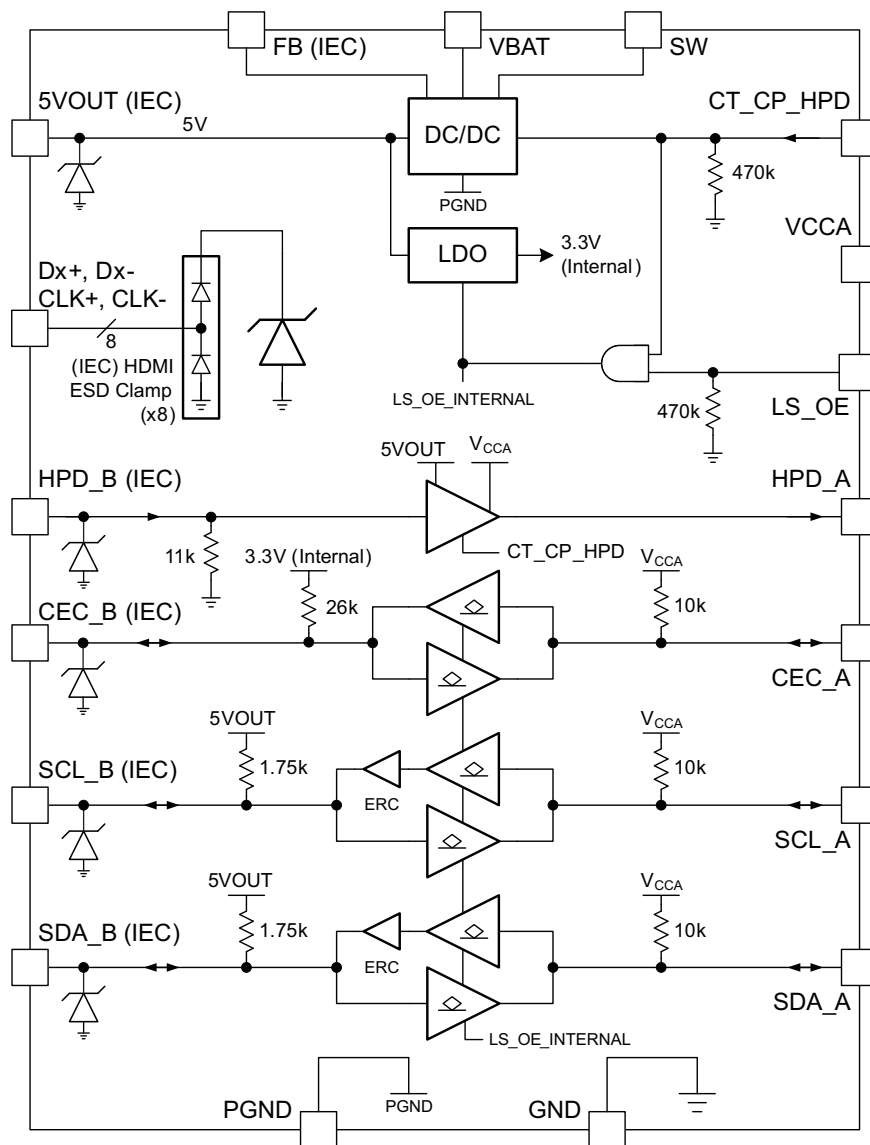
Application Schematics for HDMI controllers with TOW GPIOs for HDMI Interface Control



Some HDMI driver chips may have two GPIOs to control the HDMI interface chip. In this case a flexible power saving mode can be implemented. The LS_OE and CT_CP_HPDP are active-high enable pins. They control the TPD12S015A power saving options according to the following table:

| LS_OE | CT_CP_HPDP | VCCA | VBAT | 5VOUT | A-side Pull-ups | DDC, B-Side Pull-ups | CEC, B-Side Pull-ups | CEC LDO | DC/DC & HPD | DDC/CEC VLTs | ICC VCCA Typ | ICC VBAT Typ | Comment |
|-------|------------|------|------|-------|-----------------|----------------------|----------------------|---------|-------------|--------------|--------------|--------------|-----------------|
| L | L | 1.8V | 3.3V | Off | Off | Off | Off | Off | Off | Off | 1µA | 1µA | Fully Disabled |
| L | H | 1.8V | 3.3V | On | On | On | Off | Off | On | Off | 1µA | 30µA | DC/DC on |
| H | L | 1.8V | 3.3V | Off | Off | Off | Off | Off | Off | Off | 1µA | 1µA | Not Valid State |
| H | H | 1.8V | 3.3V | On | On | On | On | On | On | On | 13µA | 255µA | Fully On |
| X | X | 0V | 0V | Off | High-Z | High-Z | High-Z | Off | Off | Off | 0 | 0 | Power Down |
| X | X | 1.8V | 0V | Off | Low | High-Z | High-Z | Off | Off | Off | 0 | 0 | Power Down |
| X | X | 0V | 3.3V | Off | High-Z | High-Z | High-Z | Off | Off | Off | 0 | 0 | Power Down |

CIRCUIT BLOCK DIAGRAM



'3.3V (Internal)' is an internally generated voltage node for the CEC_B output buffer supply reference. An LDO generates this 3.3V from 5VOUT when LS_OE = H & CT_CP_HPDP = H.

TERMINAL FUNCTIONS

| TERMINAL | | TYPE | DESCRIPTION |
|------------------------------|------------------------|---------------|---|
| NAME | NO. | | |
| 5VOUT | F1 | Power Out | DC/DC output. The 5-V power pin can supply 55 mA regulated current to the HDMI receiver. Separate DC/DC converter control pin CT_CP_HPDP disables the DC/DC converter when operating at low-power mode. |
| CEC_A | B2 | I/O | System-side CEC bus I/O. This pin is bi-directional and referenced to V _{CCA} . |
| CEC_B | D3 | I/O | HDMI-side CEC bus I/O. This pin is bi-directional and referenced to the 3.3-V internal supply. |
| CLK-, CLK+ | G4, F4 | ESD | High-speed ESD clamp: provides ESD protection to the high-speed HDMI differential data lines |
| CT_CP_HPDP | D1 | Control | DC/DC Enable. Enables the DC/DC converter and HPD circuitry when CT_CP_HPDP = H. The CT_CP_HPDP is referenced to V _{CCA} . |
| D0-, D0+, D1-, D1+, D2-, D2+ | E4, D4, C4, B4, A4, A3 | ESD | High-speed ESD clamp: provides ESD protection to the high-speed HDMI differential data lines |
| FB | E1 | I | Feedback input. This pin is a feedback control pin for the DC/DC converter. It must be connected to 5VOUT. |
| GND | B3, C3, D2, E2 | Ground | Device ground |
| HPD_A | C2 | O | System-side output for the hot plug detect. This pin is unidirectional and is referenced to V _{CCA} . |
| HPD_B | G3 | I | HDMI-side input for the hot plug detect. This pin is unidirectional and is referenced to 5VOUT. |
| LS_OE | A1 | Control | Level shifter enable. This pin is referenced to V _{CCA} . Enables SCL, SDA, CEC level shifters, and LDO when LS_OE = H. |
| P _{GND} | G1 | Analog Ground | DC/DC converter ground. This pin should be tied externally to the system GND plane. See board layout in applications section. |
| SCL_A | B1 | I/O | System-side input/output for I ² C bus. This pin is bi-directional and referenced to V _{CCA} . |
| SCL_B | E3 | I/O | HDMI-side input/output for I ² C bus. This pin is bi-directional and referenced to 5VOUT. |
| SDA_A | C1 | I/O | System-side input/output for I ² C bus. This pin is bi-directional and referenced to V _{CCA} . |
| SDA_B | F3 | I/O | HDMI-side input/output for I ² C bus. This pin is bi-directional and referenced to 5VOUT. |
| SW | F2 | I | Switch input. This pin is the inductor input for the DC/DC converter. |
| V _{BAT} | G2 | Supply | Battery supply. This voltage is typically 2.3 V to 5.5 V |
| V _{CCA} | A2 | Supply | System-side supply. this voltage is typically 1.2 V to 3.3 V from the core microcontroller. |

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|---------------------|---|----------------------------|------|------------------------|------|
| V _{CCA} | Supply voltage range | | | 4.0 | V |
| V _{BAT} | Supply voltage range | | -0.3 | 6.0 | |
| V _I | Input voltage range | HPD_B, Dx, CLKx | -0.3 | 6.0 | V |
| | | CT_CP_HPD, LS_OE | -0.3 | 4.0 | |
| V _O | Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾ | SCL_A, SDA_A, CEC_A, HPD_A | -0.3 | 4.0 | V |
| | | SCL_B, SDA_B, CEC_B | -0.3 | 6.0 | |
| | Voltage range applied to any output in the high or low state ⁽²⁾ | SCL_A, SDA_A, CEC_A, HPD_A | -0.3 | V _{CCA} + 0.3 | |
| | | SCL_B, SDA_B, CEC_B | -0.3 | 6.0 | |
| I _{IK} | Input clamp current | V _I < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| I _{OUTMAX} | Continuous current through 5VOUT or GND | | | ±100 | mA |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses above these ratings may cause permanent damage. Exposure to "absolute maximum conditions" for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

over recommended operating free-air temperature range (unless otherwise noted)

| | | | SUPPLY | MIN | TYP | MAX | UNIT |
|------------------------------------|--|---------------------|-----------------------------------|------------------------------------|-----------------------|------------------------------------|------|
| V _{CCA} | Supply voltage | | | 1.1 | | 3.6 | V |
| V _{BAT} | Supply voltage | | | 2.3 | | 5.5 | V |
| V _{IH} | High-level input voltage | SCL_A, SDA_A, CEC_A | V _{CCA} = 1.1 V to 3.6 V | 0.7*V _{CCA} | | V _{CCA} | V |
| | | CT_CP_HPD, LS_OE | | 1 | | 3.6 | |
| | | SCL_B, SDA_B | 5VOUT = 5.0 V | 0.7*5VOUT | | 5VOUT | |
| | | CEC_B | | 0.7*3.3V (internal) ⁽¹⁾ | | 3.3V (internal) ⁽¹⁾ | |
| | | HPD_B | | 2.0 | | 5VOUT | |
| V _{IL} | Low-level input voltage | SCL_A, SDA_A, CEC_A | V _{CCA} = 1.1 V to 3.6 V | 0 | | 0.082*V _{CCA} | V |
| | | CT_CP_HPD, LS_OE | | 0 | | 0.4 | |
| | | SCL_B, SDA_B | 5VOUT = 5.0 V | 0 | | 0.3*5VOUT | |
| | | CEC_B | | 0 | | 0.3*3.3V (internal) ⁽¹⁾ | |
| | | HPD_B | | 0 | | 0.8 | |
| V _{ILC} | Low-level input voltage (contention) | SCL_A, SDA_A, CEC_A | V _{CCA} = 1.1 V to 3.6 V | 0 | | 0.065*V _{CCA} | V |
| V _{OL} - V _{ILC} | Delta between V _{OL} and V _{ILC} | SCL_A, SDA_A, CEC_A | V _{CCA} = 1.1 V to 3.6 V | | 0.1*V _{CC A} | | V |
| T _A | Operating free-air temperature | | | -40 | | 85 | °C |

(1) '3.3V (internal)' is an internally generated voltage node for the CEC_B output buffer supply reference. An LDO generates this 3.3V from 5VOUT when LS_OE = H & CT_CP_HPD = H.

ESD RATINGS

| PARAMETER | PINS | TYP | UNIT |
|----------------------------------|---|------|------|
| Human Body Model JESD22 A114-B | SCL_A, SDA_A, CEC_A, CT_CP_HPDP, LS_OE, VCCA | 2.5 | kV |
| Charged Device Model JESD22 C101 | ALL | 1000 | V |
| IEC 61000-4-2 Contact Discharge | D0+, D0-, D1+, D1-, D2+, D2-, CLK+, CLK-, SCL_B, SDA_B, CEC_B, HPD_B, 5VOUT, FB | ±8 | kV |
| Human Body Model | D0+, D0-, D1+, D1-, D2+, D2-, CLK+, CLK-, SCL_B, SDA_B, CEC_B, HPD_B, 5VOUT, FB | ±15 | kV |

ELECTRICAL CHARACTERISTICS

I_{CC}

| PARAMETER | | PIN | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-----------------------------|------------------|---------------------------------------|-----|-----|-----|------|
| I _{CCA} | Standby | V _{CCA} | I/O = High | | | 2 | µA |
| | Active | | | | | 15 | |
| I _{CCB} | Standby | V _{BAT} | CT_CP_HPDP=L, LS_OE=L, HPD_B=L | | | 2 | µA |
| | DC/DC and HPD active | | CT_CP_HPDP=H, LS_OE=L, HPD_B=L | 30 | 50 | | |
| | DC/DC, HPD, DDC, CEC active | | CT_CP_HPDP=H LS_OE=H, HPD_B=L, I/O =H | 225 | 300 | | |

High-Speed ESD Lines: Dx, CLK

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|------------------|-------------------------------------|--|-------------------|-----|------|-----|------|
| I _{OFF} | Current from IO port to supply pins | V _{CC} = 0 V, V _{IO} = 3.3 V | | | 0.01 | 0.5 | µA |
| V _{DL} | Diode forward voltage | I _D = 8 mA, | Lower clamp diode | | 0.85 | 1.0 | V |
| R _{DYN} | Dynamic resistance | I = 1 A | D, CLK | | 1 | | Ω |
| C _{IO} | IO capacitance | V _{CC} = 5 V V _{IO} = 2.5 V | D, CLK | | 1.3 | | pF |
| V _{BR} | Break-down voltage | I _{IO} = 1mA | | 9 | | 12 | V |

DC-DC Converter

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT | |
|-------------------------|--|---|--|-----|-----|------|----------|------|
| V _{BAT} | Input voltage range | | | 2.3 | | 5.5 | V | |
| 5VOUT | Total DC output voltage | Includes voltage references, DC load / line regulations, process and temperature | | 4.9 | 5 | 5.13 | V | |
| TOVA | Total output voltage accuracy | Includes voltage references, DC load / line regulations, transient load / line regulations, ripple, process and temperature | | 4.8 | 5 | 5.3 | V | |
| V _{O_ripple} | Output voltage ripple, loaded | I _O = 65 mA | | | | 20 | mV (p-p) | |
| F _{clk} | Internal operating frequency | V _{BAT} = 2.3 V to 5.5 V | | | | 3.5 | MHz | |
| t _{start} | Startup time | From CT_CP_HPDP input to 5 V power output 90% point | | | | 300 | µs | |
| I _O | Output current | V _{BAT} = 2.3 V to 5.5 V | | | | 55 | mA | |
| | Reverse leakage current V _O | CT_CP_HPDP= L, V _O = 5.5 V | | | | 2.5 | µA | |
| V _O | Leakage current from battery to V _O | CT_CP_HPDP= L | | | | 5 | µA | |
| | | | | | | | | |
| V _{BATUVT} | Under voltage lockout threshold | Falling | | | | 2 | V | |
| | | Rising | | | | 2.1 | V | |
| V _{BATOV} | Over voltage lockout threshold | Falling | | | | 5.9 | V | |
| | | Rising | | | | 6.0 | V | |
| Line transient response | | V _{BAT} = 3.6 V, a pulse of 217Hz 600 mVp-p square wave, I _O = 20/65 mA | | | | ±25 | ±50 | mVpk |

DC-DC Converter (continued)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|---|---|-----|-----|-----|--------------------|
| Load transient response | | $V_{BAT} = 3.6\text{ V}$, $I_O = 5\text{ to }65\text{ mA}$, pulse of $10\text{ }\mu\text{s}$, $t_r = t_f = 0.1\text{ }\mu\text{s}$ | | 50 | | mVpk |
| I_{DD} (idle) | Power supply current from V_{BAT} to DC/DC, enabled, unloaded | $I_O = 0\text{ mA}$ | | 30 | 50 | μA |
| I_{DD} (disabled) | Power supply current from V_{BAT} , DC/DC Disabled, Unloaded | $V_{BAT} = 2.3\text{ V to }5.5\text{ V}$, $I_O = 0\text{ mA}$, CT_CP_HPDLow | | | 2 | μA |
| I_{DD} (system off) | Power supply current from V_{BAT} , $V_{CCA} = 0\text{V}$ | $V_{CCA} = 0\text{ V}$ | | | 5 | μA |
| I_{inrush} (startup) | Inrush current, average over $T_{startup}$ time | $V_{BAT} = 2.3\text{ V to }5.5\text{ V}$, $I_O = 65\text{ mA}$ | | 100 | | mA |
| T_{SD} | Thermal shutdown | Increasing junction temperature | | 140 | | $^{\circ}\text{C}$ |
| ΔT_{SD} | Thermal shutdown hysteresis | Decreasing junction temperature | | 20 | | $^{\circ}\text{C}$ |
| I_{SC} | Short circuit current limit from output | 5Ω short to GND | | | 500 | mA |

Passive Components

| PARAMETER | | TYP | UNIT |
|------------|-----------------------------------|-----|---------------|
| L_{IN} | External inductor, 0805 footprint | 1 | μH |
| C_{IN} | Input capacitor, 0603 footprint | 4.7 | μF |
| C_{OUT} | Output capacitor, 0603 footprint | 4.7 | μF |
| C_{VCCA} | Input capacitor, 0402 footprint | 0.1 | μF |

Voltage Level Shifter: SCL, SDA Lines (x_A/x_B Ports)
 $T_A = -40^{\circ}\text{C}$ to 85°C unless otherwise specified

| PARAMETER | | TEST CONDITIONS | V_{CCA} | MIN | TYP | MAX | UNIT |
|-------------------------|--|---|---|-----------------------|------|---------|---------------|
| V_{OHA} | | $I_{OH} = -10\text{ }\mu\text{A}$, $V_I = V_{IH}$ | 1.1 V to 3.6 V | $V_{CCA} \times 0.8$ | | | V |
| V_{OLA} | | $I_{OL} = 10\text{ }\mu\text{A}$, $V_I = V_{IL}$ | 1.1 V to 3.6 V | $V_{CCA} \times 0.17$ | | | V |
| V_{OHB} | | $I_{OH} = -10\text{ }\mu\text{A}$, $V_I = V_{IH}$ | | $5V_{OUT} \times 0.9$ | | | V |
| V_{OLB} | | $I_{OL} = 3\text{ mA}$, $V_I = V_{IL}$ | | | | 0.4 | V |
| ΔV_T hysteresis | SDx_A ($V_{T+} - V_{T-}$) | | 1.1 V to 3.6 V | | 40 | | mV |
| | SDx_B ($V_{T+} - V_{T-}$) | | 1.1 V to 3.6 V | | 400 | | |
| R_{PU} | (Internal pullup) | SCL_A, SDA_A, | Internal pullup connected to V_{CCA} rail | | 10 | | k Ω |
| | | SCL_B, SDA_B, | Internal pullup connected to 5 V rail | | 1.75 | | |
| $I_{PULLUPAC}$ | Transient boosted pullup current (rise time accelerator) | SCL_B, SDA_B, | Internal pullup connected to 5 V rail | | 15 | | mA |
| I_{OFF} | A port | $V_{CCA} = 0\text{ V}$, V_I or $V_O = 0\text{ to }3.6\text{ V}$ | | 0 V | | ± 5 | μA |
| | B port | $5V_{OUT} = 0\text{ V}$, V_I or $V_O = 0\text{ to }5.5\text{ V}$ | | 0 V to 3.6 V | | ± 5 | |
| I_{OZ} | B port | $V_O = V_{CCO}$ or GND | | 1.1 V to 3.6 V | | ± 5 | μA |
| | A port | $V_I = V_{CCI}$ or GND | | 1.1 V to 3.6 V | | ± 5 | |

Voltage Level Shifter: CEC Lines (x_A/x_B Ports)

T_A = –40°C to 85°C unless otherwise specified

| PARAMETER | | TEST CONDITIONS | V _{CCA} | MIN | TYP | MAX | UNIT |
|-----------------------------------|--|---|------------------|--------------------------------------|-----|-----|------|
| V _{OHA} | | I _{OH} = –10 μA, V _I = V _{IH} | 1.1 V to 3.6 V | V _{CCA} × 0.8 | | | V |
| V _{OLA} | | I _{OL} = 10 μA, V _I = V _{IL} | 1.1 V to 3.6 V | V _{CCA} × 0.17 | | | V |
| V _{OHB} | | I _{OH} = –10 μA, V _I = V _{IH} | | 3.3V (internal) × 0.9 ⁽¹⁾ | | | V |
| V _{OLB} | | I _{OL} = 3 mA, V _I = V _{IL} | | 0.4 | | | V |
| ΔV _T hysteresis | CEC_A (V _{T+} – V _{T–}) | | 1.1 V to 3.6 V | 40 | | | mV |
| | CEC_B (V _{T+} – V _{T–}) | | 1.1 V to 3.6 V | 300 | | | |
| R _{PU} (Internal pullup) | CEC_A | Internal pullup connected to V _{CCA} rail | | 10 | | | kΩ |
| | CEC_B | Internal pullup connected to internal 3.3 V rail | | 26 | | | |
| I _{OFF} | A port | V _{CCA} = 0 V, V _I or V _O = 0 to 3.6 V | 0 V | ±5 | | | μA |
| | B port | 5VOUT = 0 V, V _I or V _O = 0 to 5.5 V | 0 V to 3.6 V | ±1.8 | | | |
| I _{OZ} | B port | V _O = V _{CCO} or GND | 1.1 V to 3.6 V | ±5 | | | μA |
| | A port | V _I = V _{CCI} or GND | 1.1 V to 3.6 V | ±5 | | | |

(1) '3.3V (internal)' is an internally generated voltage node for the CEC_B output buffer supply reference. An LDO generates this 3.3V from 5VOUT when LS_OE = H & CT_CP_HPD = H

Voltage Level Shifter: HPD Line (x_A/x_B Ports)

T_A = –40°C to 85°C unless otherwise specified

| PARAMETER | | TEST CONDITIONS | V _{CCA} | MIN | TYP | MAX | UNIT |
|-------------------------------------|--|---|------------------|------------------------|-----|-----|------|
| V _{OHA} | | I _{OH} = –3 mA, V _I = V _{IH} | 1.1 V to 3.6 V | V _{CCA} × 0.7 | | | V |
| V _{OLA} | | I _{OL} = 3 mA, V _I = V _{IL} | 1.1 V to 3.6 V | 0.4 | | | V |
| ΔV _T hysteresis | HPD_B (V _{T+} – V _{T–}) | | 1.1 V to 3.6 V | 200 | | | mV |
| R _{PD} (Internal pulldown) | HPD_B, | Internal pulldown connected to GND | | 11 | | | kΩ |
| I _{OZ} | A port | V _I = V _{CCI} or GND | 3.6 V | ±5 | | | μA |

LS_OE, CT_CP_HPD

T_A = –40°C to 85°C unless otherwise specified

| PARAMETER | TEST CONDITIONS | V _{CCA} | MIN | TYP | MAX | UNIT |
|----------------|--|------------------|-----|-----|-----|------|
| I _I | V _I = V _{CCA} or GND | 1.1 V to 3.6 V | | | ±12 | μA |

I/O Capacitance

T_A = –40°C to 85°C unless otherwise specified

| PARAMETER | TEST CONDITIONS | V _{CCA} | MIN | TYP | MAX | UNIT |
|-----------------|-----------------|---|----------------|-----|-----|------|
| C _I | Control inputs | V _I = 1.89 V or GND, AC input = 30 mV(p-p); f = 10 MHz | 1.1 V to 3.6 V | 7.1 | | pF |
| C _{IO} | A port | V _O = 1.89 V or GND, AC input = 30 mV(p-p); f = 10 MHz, CT_CP_HPD = H, LS_OE = L | 1.1 V to 3.6 V | 8.3 | | pF |
| | B port | V _O = 5.0 V or GND, AC input = 30 mV(p-p); f = 10 MHz, CT_CP_HPD = H, LS_OE = L | 3.3 V | 15 | | pF |

I/O Capacitance (continued)
 $T_A = -40^{\circ}\text{C}$ to 85°C unless otherwise specified

| PARAMETER | | TEST CONDITIONS | V_{CCA} | MIN | TYP | MAX | UNIT |
|-----------------|-----------------|---|-----------|-----|-----|-----|------|
| C _{IO} | SCL_B, SDA_B | $V_{BAT} = 0\text{ V}$, $V_{bias} = 2.5\text{ V}$; AC input = 3.5 V(p-p); f = 100 kHz | 0 V | | 20 | | pF |
| | CEC_B | $V_{BAT} = 0\text{ V}$, $V_{bias} = 1.65\text{ V}$; AC input = 2.5 V(p- p); f = 100 kHz | 0 V | | 20 | | pF |
| | | $V_{BAT} = 3.3\text{ V}$, $V_{bias} = 1.65\text{ V}$; AC input = 2.5 V(p- p); f = 100 kHz, CT_CP_HPDP = H, LS_OE = L | 3.3 V | | 20 | | pF |

SWITCHING CHARACTERISTICS

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------|-------------------------------|-----------------|-----|-----|-----|------|
| C _L | Bus load capacitance (B side) | | | | 750 | pF |
| | Bus load capacitance (A side) | | | | 15 | |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); V_{CCA} = 1.2V

V_{CCA} = 1.2 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-----------------------------|--------|----------------------|-----|-----|-----|------|
| t _{PHL} | Propagation delay | A to B | DDC Channels Enabled | | 344 | | ns |
| | | B to A | | 355 | | | |
| t _{PLH} | Propagation delay | A to B | DDC Channels Enabled | | 452 | | ns |
| | | B to A | | 178 | | | |
| t _f | A port fall time | A Port | DDC Channels Enabled | | 138 | | ns |
| | B port fall time | B Port | | 83 | | | |
| t _r | A port rise time | A Port | DDC Channels Enabled | | 194 | | ns |
| | B port rise time | B Port | | 92 | | | |
| f _{MAX} | Maximum switching frequency | | DDC Channels Enabled | 400 | | | kHz |

Voltage Level Shifter: CEC Line (x_A & x_B ports); V_{CCA} = 1.2V

V_{CCA} = 1.2 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-------|-----|-----|------|
| t _{PLH} | Propagation delay | A to B | CEC Channels Enabled | | 445 | | ns |
| | | B to A | | 337 | | | |
| t _{PLH} | | A to B | | | 13 | | μs |
| | | B to A | | 0.266 | | | |
| t _f | A port fall time | A Port | CEC Channels Enabled | | 140 | | ns |
| | B port fall time | B Port | | 96 | | | |
| t _r | A port rise time | A Port | CEC Channels Enabled | | 202 | | ns |
| | B port rise time | B Port | | 15 | | | |

Voltage Level Shifter: HPD Line (x_A & x_B ports); V_{CCA} = 1.2V

V_{CCA} = 1.2 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-----|------|-----|------|
| t _{PLH} | Propagation delay | B to A | CEC Channels Enabled | | 10 | | μs |
| t _{PLH} | | B to A | | 9 | | | |
| t _f | A port fall time | A Port | CEC Channels Enabled | | 0.67 | | ns |
| t _r | A port rise time | A Port | CEC Channels Enabled | | 0.74 | | ns |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); V_{CCA} = 1.5V

V_{CCA} = 1.5 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-----|-----|-----|------|
| t _{PLH} | Propagation delay | A to B | DDC Channels Enabled | | 335 | | ns |
| | | B to A | | 265 | | | |
| t _{PLH} | | A to B | | | 438 | | |
| | | B to A | | 169 | | | |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); VCCA = 1.5V (continued)
 $V_{CCA} = 1.5\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-----------------------------|--------|----------------------|-----|-----|-----|------|
| t_f | A port fall time | A Port | DDC Channels Enabled | | 110 | | ns |
| | B port fall time | B Port | | | 83 | | |
| t_r | A port rise time | A Port | DDC Channels Enabled | | 190 | | ns |
| | B port rise time | B Port | | | 92 | | |
| f_{MAX} | Maximum switching frequency | | DDC Channels Enabled | 400 | | | kHz |

Voltage Level Shifter: CEC Line (x_A & x_B ports); VCCA = 1.5V
 $V_{CCA} = 1.5\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------|--------|----------------------|-----|-------|-----|---------------|
| t_{PLH} | Propagation delay | A to B | CEC Channels Enabled | | 437 | | ns |
| | | B to A | | | 267 | | |
| t_{PLH} | Propagation delay | A to B | CEC Channels Enabled | | 13 | | μs |
| | | B to A | | | 0.264 | | |
| t_f | A port fall time | A Port | CEC Channels Enabled | | 110 | | ns |
| | B port fall time | B Port | | | 96 | | |
| t_r | A port rise time | A Port | CEC Channels Enabled | | 202 | | ns |
| | B port rise time | B Port | | | 15 | | |

Voltage Level Shifter: HPD Line (x_A & x_B ports); VCCA = 1.5V
 $V_{CCA} = 1.5\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------|--------|----------------------|-----|------|-----|---------------|
| t_{PLH} | Propagation delay | B to A | CEC Channels Enabled | | 10 | | μs |
| | | B to A | | | 9 | | |
| t_f | A port fall time | A Port | CEC Channels Enabled | | 0.47 | | ns |
| t_r | A port rise time | A Port | CEC Channels Enabled | | 0.51 | | ns |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); VCCA = 1.8V
 $V_{CCA} = 1.8\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-----------------------------|--------|----------------------|-----|-----|-----|------|
| t_{PLH} | Propagation delay | A to B | DDC Channels Enabled | | 334 | | ns |
| | | B to A | | | 229 | | |
| t_{PLH} | Propagation delay | A to B | DDC Channels Enabled | | 431 | | |
| | | B to A | | | 169 | | |
| t_f | A port fall time | A Port | DDC Channels Enabled | | 94 | | ns |
| | B port fall time | B Port | | | 83 | | |
| t_r | A port rise time | A Port | DDC Channels Enabled | | 191 | | ns |
| | B port rise time | B Port | | | 92 | | |
| f_{MAX} | Maximum switching frequency | | DDC Channels Enabled | 400 | | | kHz |

Voltage Level Shifter: CEC Line (x_A & x_B ports); VCCA = 1.8V

V_CCA = 1.8 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-----|------|-----|------|
| t _{PLH} | Propagation delay | A to B | CEC Channels Enabled | | 441 | | ns |
| | | B to A | | | 231 | | |
| t _{PLH} | | A to B | | | 13 | | μs |
| | | B to A | | | 0.26 | | |
| t _f | A port fall time | A Port | CEC Channels Enabled | | 94 | | ns |
| | B port fall time | B Port | | | 96 | | |
| t _r | A port rise time | A Port | CEC Channels Enabled | | 201 | | ns |
| | B port rise time | B Port | | | 15 | | |

Voltage Level Shifter: HPD Line (x_A & x_B ports); VCCA = 1.8V

V_CCA = 1.8 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-----|------|-----|------|
| t _{PLH} | Propagation delay | B to A | CEC Channels Enabled | | 10 | | μs |
| | | B to A | | | 9 | | |
| t _f | A port fall time | A Port | CEC Channels Enabled | | 0.41 | | ns |
| t _r | A port rise time | A Port | CEC Channels Enabled | | 0.45 | | ns |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); VCCA = 2.5V

V_CCA = 2.5 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-----------------------------|--------|----------------------|-----|-----|-----|------|
| t _{PLH} | Propagation delay | A to B | DDC Channels Enabled | | 330 | | ns |
| | | B to A | | | 182 | | |
| t _{PLH} | | A to B | | | 423 | | ns |
| | | B to A | | | 166 | | |
| t _f | A port fall time | A Port | DDC Channels Enabled | | 79 | | ns |
| | B port fall time | B Port | | | 83 | | |
| t _r | A port rise time | A Port | DDC Channels Enabled | | 188 | | ns |
| | B port rise time | B Port | | | 92 | | |
| f _{MAX} | Maximum switching frequency | | DDC Channels Enabled | 400 | | | kHz |

Voltage Level Shifter: CEC Line (x_A & x_B ports); VCCA = 2.5V

V_CCA = 2.5 V

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|------------------|-------------------|--------|----------------------|-----|-------|-----|------|
| t _{PLH} | Propagation delay | A to B | CEC Channels Enabled | | 454 | | ns |
| | | B to A | | | 184 | | |
| t _{PLH} | | A to B | | | 13 | | μs |
| | | B to A | | | 0.255 | | |
| t _f | A port fall time | A Port | CEC Channels Enabled | | 79 | | ns |
| | B port fall time | B Port | | | 96 | | |
| t _r | A port rise time | A Port | CEC Channels Enabled | | 194 | | ns |
| | B port rise time | B Port | | | 15 | | |

Voltage Level Shifter: HPD Line (x_A & x_B ports); VCCA = 2.5V
 $V_{CCA} = 2.5\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------|--------|----------------------|-----|------|-----|---------------|
| t_{PLH} | Propagation delay | B to A | CEC Channels Enabled | | 10 | | μs |
| t_{PLH} | | B to A | | 9 | | | |
| t_f | A port fall time | A Port | CEC Channels Enabled | | 0.37 | | ns |
| t_r | A port rise time | A Port | CEC Channels Enabled | | 0.39 | | ns |

Voltage Level Shifter: SCL, SDA Lines (x_A & x_B ports); VCCA = 3.3V
 $V_{CCA} = 3.3\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-----------------------------|--------|----------------------|-----|-----|-----|------|
| t_{PLH} | Propagation delay | A to B | DDC channels enabled | | 323 | | ns |
| | | B to A | | 158 | | | |
| t_{PLH} | | A to B | | 421 | | | |
| | | B to A | | 162 | | | |
| t_f | A port fall time | A Port | DDC channels enabled | | 71 | | ns |
| | B port fall time | B Port | | 84 | | | |
| t_r | A port rise time | A Port | DDC channels enabled | | 188 | | ns |
| | B port rise time | B Port | | 92 | | | |
| f_{MAX} | Maximum switching frequency | | DDC channels enabled | 400 | | | kHz |

Voltage Level Shifter: CEC Line (x_A & x_B ports); VCCA = 3.3V
 $V_{CCA} = 3.3\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------|--------|----------------------|-------|---------------|-----|------|
| t_{PLH} | Propagation delay | A to B | CEC channels enabled | | 450 | | ns |
| | | B to A | | 160 | | | |
| t_{PLH} | | A to B | | 13 | μs | | |
| | | B to A | | 0.251 | | | |
| t_f | A port fall time | A Port | CEC channels enabled | | 71 | | ns |
| | B port fall time | B Port | | 96 | | | |
| t_r | A port rise time | A Port | CEC channels enabled | | 194 | | ns |
| | B port rise time | B Port | | 15 | μs | | |

Voltage Level Shifter: HPD Line (x_A & x_B ports); VCCA = 3.3V
 $V_{CCA} = 3.3\text{ V}$

| PARAMETER | | PINS | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------|--------|----------------------|-----|------|-----|---------------|
| t_{PLH} | Propagation delay | B to A | CEC channels enabled | | 10 | | μs |
| t_{PLH} | | B to A | | 9 | | | |
| t_f | A port fall time | A Port | CEC channels enabled | | 0.35 | | ns |
| t_r | A port rise time | A Port | CEC channels enabled | | 0.37 | | ns |

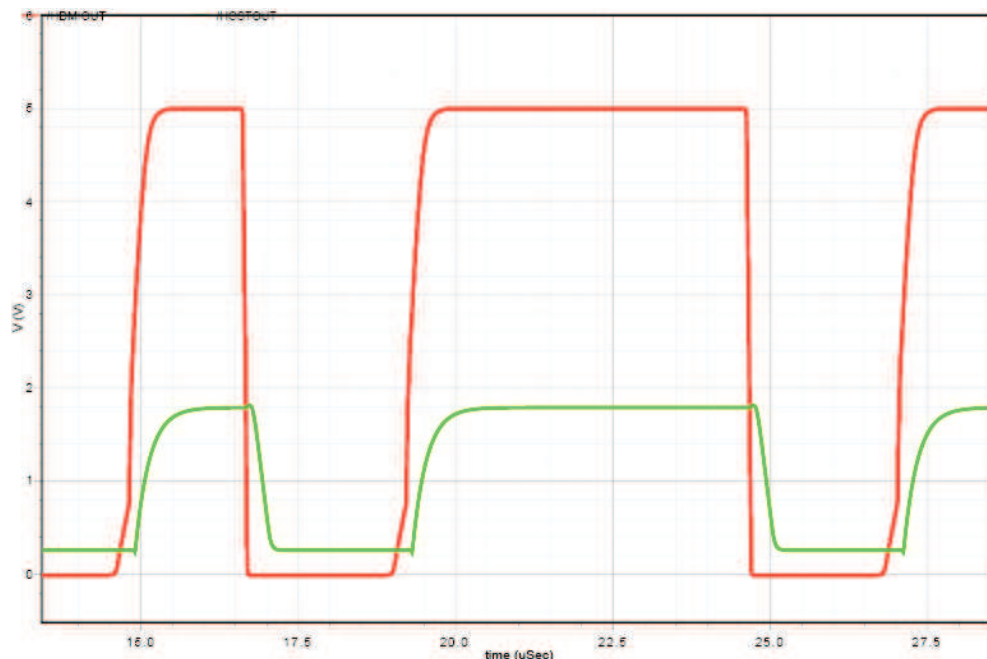


Figure 3. DDC/CEC Level Shifter Operation (B to A Direction)

Rise-Time Accelerators

The HDMI cable side of the DDC lines incorporates rise-time accelerators to support the high capacitive load on the HDMI cable side. The rise time accelerator boosts the cable side DDC signal independent of which side of the bus is releasing the signal.

Remark

Ground offset between the TPD12S015A ground and the ground of devices on port A of the TPD12S015A must be avoided. The reason for this cautionary remark is that a CMOS/NMOS open-drain capable of sinking 3 mA of current at 0.4 V will have an output resistance of 133 ohms or less ($R = E / I$). Such a driver will share enough current with the port A output pull-down of the TPD12S015A to be seen as a LOW as long as the ground offset is zero. If the ground offset is greater than 0 V, then the driver resistance must be less. Since VILC can be as low as 90 mV at cold temperatures and the low end of the current distribution, the maximum ground offset should not exceed 50 mV. Bus repeaters that use an output offset are not interoperable with the port A of the TPD12S015A as their output LOW levels will not be recognized by the TPD12S015A as a LOW. If the TPD12S015A is placed in an application where the VIL of port A of the TPD12S015A does not go below its VILC it will pull port B LOW initially when port A input transitions LOW but the port B will return HIGH, so it will not reproduce the port A input on port B. Such applications should be avoided. Port B is interoperable with all I²C bus slaves, masters and repeaters.

CEC Level Shift Operation

The CEC level shift function operates in the same manner as the DDC lines except that the CEC line does not need the rise time accelerator function.

Internal Pullup Resistor

The TPD12S015A has incorporated all the required pullup and pulldown resistors at the interface pins. The system is designed to work properly with no external pullup resistors on the DDC, CEC, and HPD lines. For proper system operation no external resistors should be placed at the A and B ports. If there is internal pullups at the host processor, they should be disabled.

Power-Save Mode

The TPD12S015A integrates a power save mode to improve efficiency at light load. In power save mode the converter only operates when the output voltage trips below a set threshold voltage. It ramps up the output voltage with several pulses and goes into power save mode once the output voltage exceeds the set threshold voltage. The PFM mode is left and PWM mode entered in case the output current can not longer be supported in PFM mode.

Under-Voltage Lockout

The under voltage lockout circuit prevents the DC/DC converter from malfunctioning at low input voltages and from excessive discharge of the battery. It disables the output stage of the converter once the falling V_{IN} trips the under-voltage lockout threshold V_{BATUV} . The under-voltage lockout threshold V_{BATUV} for falling V_{IN} is typically 2.0V. The device starts operation once the rising V_{IN} trips under-voltage lockout threshold V_{BATUV} again at typical 2.1 V.

Enable

The DC/DC converter is enabled when the CT_CP_HPDP is set to high. At first, the internal reference is activated and the internal analog circuits are settled. Afterwards, the soft start is activated and the output voltage is ramped up. The output voltage reaches its nominal value in typically 250 μ s after the device has been enabled. The CT_CP_HPDP input can be used to control power sequencing in a system with various DC/DC converters. The CT_CP_HPDP pin can be connected to the output of another converter, to drive the EN pin high and getting a sequencing of supply rails. With CT_CP_HPDP = GND, the dc/dc enters shutdown mode.

Soft Start

The DC/DC converter has an internal soft start circuit that controls the ramp up of the output voltage. The output voltage reaches its nominal value within t_{Start} of typically 250 μ s after CT_CP_HPDP pin has been pulled to high level. The output voltage ramps up from 5% to its nominal value within t_{Ramp} of 300 μ s. This limits the inrush current in the converter during start up and prevents possible input voltage drops when a battery or high impedance power source is used. During soft start, the switch current limit is reduced to 300 mA until the output voltage reaches V_{IN} . Once the output voltage trips this threshold, the device operates with its nominal current limit ILIMF.

Inductor Selection

To make sure that the TPD12S015A devices can operate, an inductor must be connected between pin V_{BAT} and pin L. A boost converter normally requires two main passive components for storing energy during the conversion. A boost inductor and a storage capacitor at the output are required. To select the boost inductor, it is recommended to keep the possible peak inductor current below the current limit threshold of the power switch in the chosen configuration. The highest peak current through the inductor and the switch depends on the output load, the input (V_{BAT}), and the output voltage (5VOUT). Estimation of the maximum average inductor current can be done using [Equation 1](#).

$$I_{L_MAX} \approx I_{OUT} \times \frac{V_{OUT}}{\eta \times V_{IN}} \quad (1)$$

For example, for an output current of 55 mA at 5VOUT, approx 150 mA of average current flows through the inductor at a minimum input voltage of 2.3 V.

The second parameter for choosing the inductor is the desired current ripple in the inductor. Normally, it is advisable to work with a ripple of less than 20% of the average inductor current. A smaller ripple reduces the magnetic hysteresis losses in the inductor, as well as output voltage ripple and EMI. But in the same way, regulation time at load changes rises. In addition, a larger inductor increases the total system size and cost. With these parameters, it is possible to calculate the value of the minimum inductance by using [Equation 2](#).

$$L_{MIN} \approx \frac{V_{IN} \times (V_{OUT} - V_{IN})}{\Delta I_L \times f \times V_{OUT}} \quad (2)$$

Parameter f is the switching frequency and ΔI_L is the ripple current in the inductor, i.e., $20\% \times I_L$. With this calculated value and the calculated currents, it is possible to choose a suitable inductor. In typical applications a $1.0 \mu\text{H}$ inductance is recommended. The device has been optimized to operate with inductance values between $1.0 \mu\text{H}$ and $1.3 \mu\text{H}$. It is recommended that an inductance value of at least $1.0 \mu\text{H}$ is used, even if [Equation 2](#) yields something lower. Care has to be taken that load transients and losses in the circuit can lead to higher currents as estimated in Equation 3. Also, the losses in the inductor caused by magnetic hysteresis losses and copper losses are a major parameter for total circuit efficiency.

With the chosen inductance value, the peak current for the inductor in steady state operation can be calculated. [Equation 3](#) shows how to calculate the peak current I .

$$I_{L(\text{peak})} = \frac{V_{IN} \times D}{2 \times f \times L} + \frac{I_{OUT}}{(1-D) \times \eta} \quad (3)$$

$$\text{where } D = \frac{V_{OUT} - V_{IN}}{V_{OUT}}$$

This would be the critical value for the current rating for selecting the inductor. It also needs to be taken into account that load transients and error conditions may cause higher inductor currents.

Input Capacitor

Because of the nature of the boost converter having a pulsating input current, a low ESR input capacitor is required to prevent large voltage transients that can cause misbehavior of the device or interferences with other circuits in the system. At least $1.2 \mu\text{F}$ input capacitor is recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. It is recommended to place a ceramic capacitor as close as possible to the V_{IN} and GND pins and better to use a $4.7 \mu\text{F}$ capacitor, in order to improve the input noise filtering.

Output Capacitor

For the output capacitor, it is recommended to use small ceramic capacitors placed as close as possible to the V_{OUT} and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which can not be placed close to the IC, using a smaller ceramic capacitor in parallel to the large one is recommended. This small capacitor should be placed as close as possible to the V_{OUT} and GND pins of the IC. To get an estimate of the recommended minimum output capacitance, [Equation 4](#) can be used.

$$C_{\min} = \frac{I_{OUT} \times (V_{OUT} - V_{IN})}{f \times \Delta V \times V_{OUT}} \quad (4)$$

Parameter f is the switching frequency and ΔV is the maximum allowed ripple. With a chosen ripple voltage of 10 mV , a minimum effective capacitance of $2.7 \mu\text{F}$ is needed. The total ripple is larger due to the ESR of the output capacitor. This additional component of the ripple can be calculated using $\Delta V_{\text{ESR}} = I_{OUT} \times R_{\text{ESR}}$

A capacitor with a value in the range of the calculated minimum should be used. This is required to maintain control loop stability. There are no additional requirements regarding minimum ESR. There is no upper limit for the output capacitance value. Larger capacitors cause lower output voltage ripple as well as lower output voltage drop during load transients.

Note that ceramic capacitors have a DC Bias effect, which will have a strong influence on the final effective capacitance needed. Therefore the right capacitor value has to be chosen very carefully. Package size and voltage rating in combination with material are responsible for differences between the rated capacitor value and the effective capacitance. The minimum effective capacitance value should be $1.2 \mu\text{F}$ but preferred value is about $4.7 \mu\text{F}$

Table 1. Passive Components: Recommended Minimum Effective Values

| COMPONENT | MIN | TARGET | MAX | UNIT |
|-----------|-----|--------|-----|---------|
| C_{IN} | 1.2 | 4.7 | 6.5 | μF |
| C_{OUT} | 1.2 | 4.7 | 10 | μF |
| L_{IN} | 0.7 | 1 | 1.3 | μH |

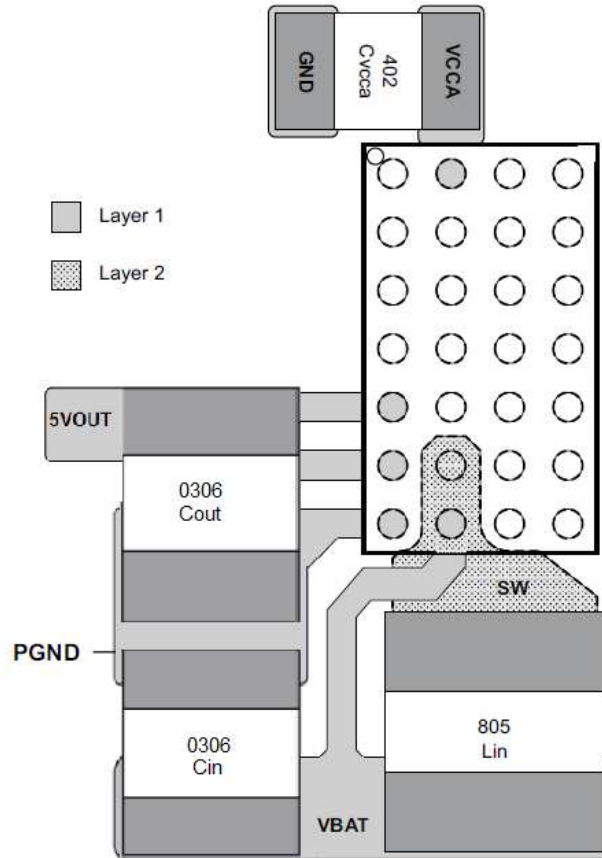


Figure 4. Board Layout (DC-DC Components) (Top View)

List of components:

- L_{IN} = MURATA LQM21PN1R0MC0 (1.0 μH , 800 mA, 0805, Shielded)
- C_{IN} = C_{OUT} = MURATA LLL31MR70J475MA01 (4.7 μF , Low ESL type, 6.3 V, 0306, X7R)
- C_{VCCA} = MURATA GRM155R60J475ME87D (0.1 μF , 6.3 V, 0402, X5R)

TPD12S015A EVM Layout

The TPD12S015A EVM has been designed for HDMI functional testing and includes both HDMI A-type and HDMI C-type connectors. Board jumpers enable and disable the dc-dc and level shifting circuitry. There are two supply terminals (VCCA and VBAT) and one GND terminal at the edge of the board. High speed lines were kept on top and bottom layers and matched for 50 Ω line to GND. All the high speed lines are matched to minimize the skew. The board has three test fixtures for testing the TPD12S015A in the following environments:

- The top segment enables system designers to test the TPD12S015A using the HDMI Class A connector
- The middle segment enables the system designers to test to test the TPD12S015A using the HDMI Class C connector
- The bottom segment enables the system designers to test signal integrity and eye pattern using differential probe.

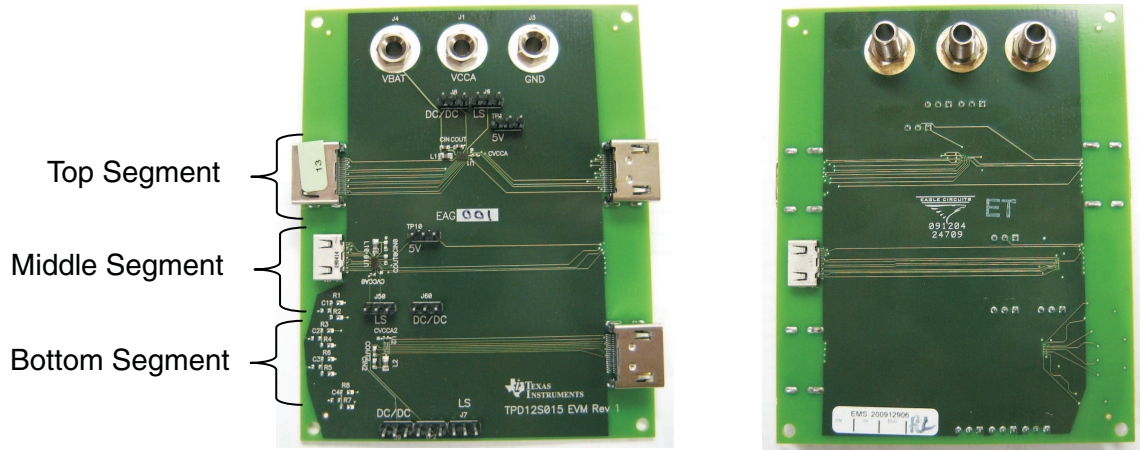


Figure 5. TPD12S015A EVM Top and Bottom View

The EVM board has 6 layers. The signal stack up is described below:

| BOARD LAYER | DESCRIPTION |
|-------------|-------------------------|
| Layer 1 | High-speed signal layer |
| Layer 2 | Ground plane |
| Layer 3 | Control signal layer |
| Layer 4 | Control signal layer |
| Layer 5 | Power plane |
| Layer 6 | High-speed signal layer |

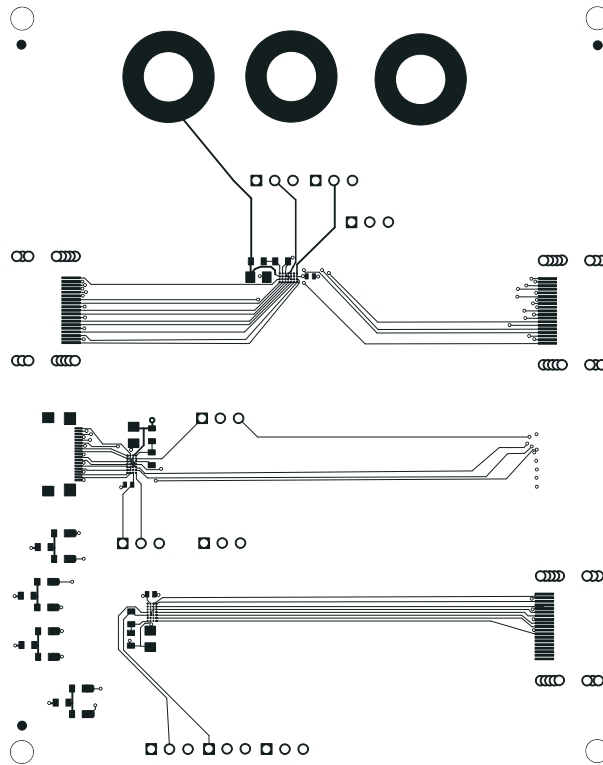


Figure 6. Layer 1: High-Speed Signal layer

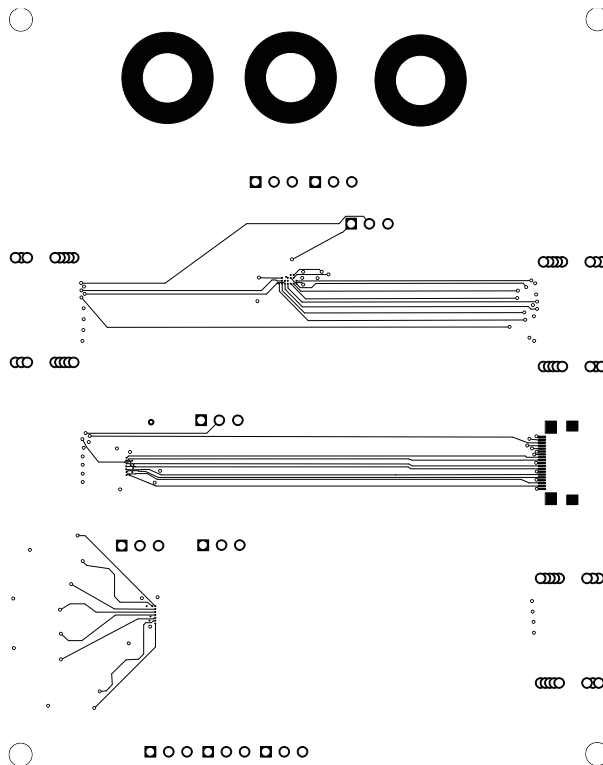


Figure 7. Layer 6: High-Speed Signal layer

TYPICAL CHARACTERISTICS

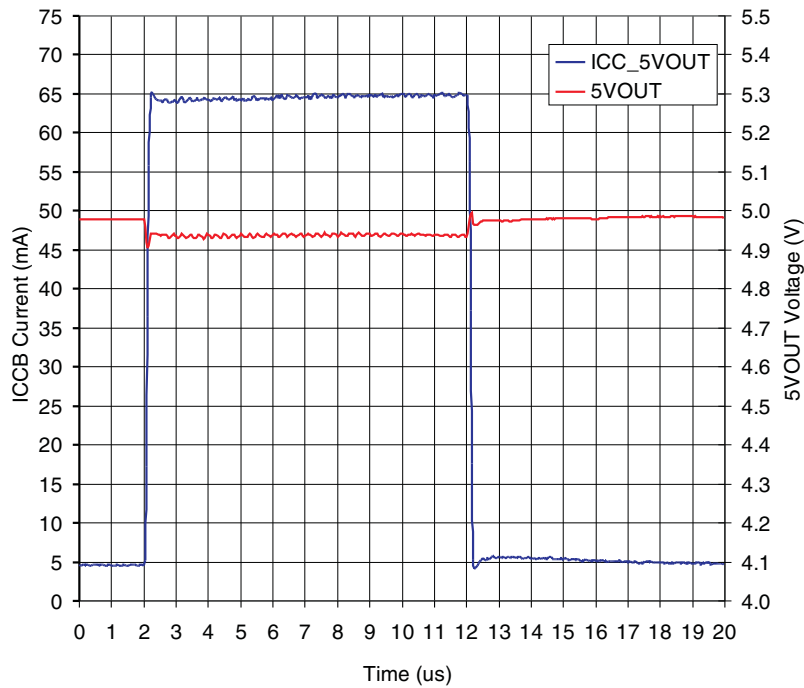


Figure 8. Load Transient Response

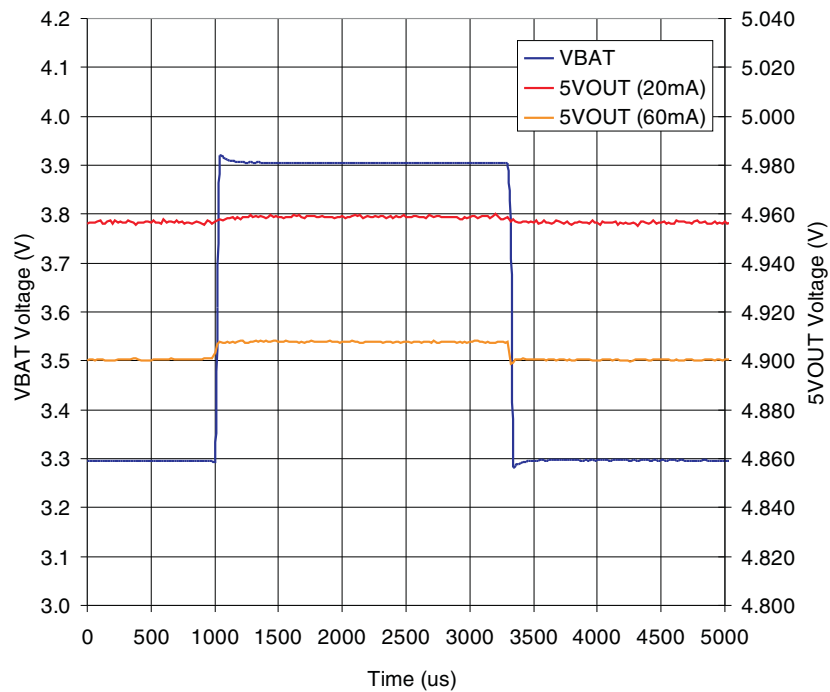


Figure 9. Line Transient Response

TYPICAL CHARACTERISTICS (continued)

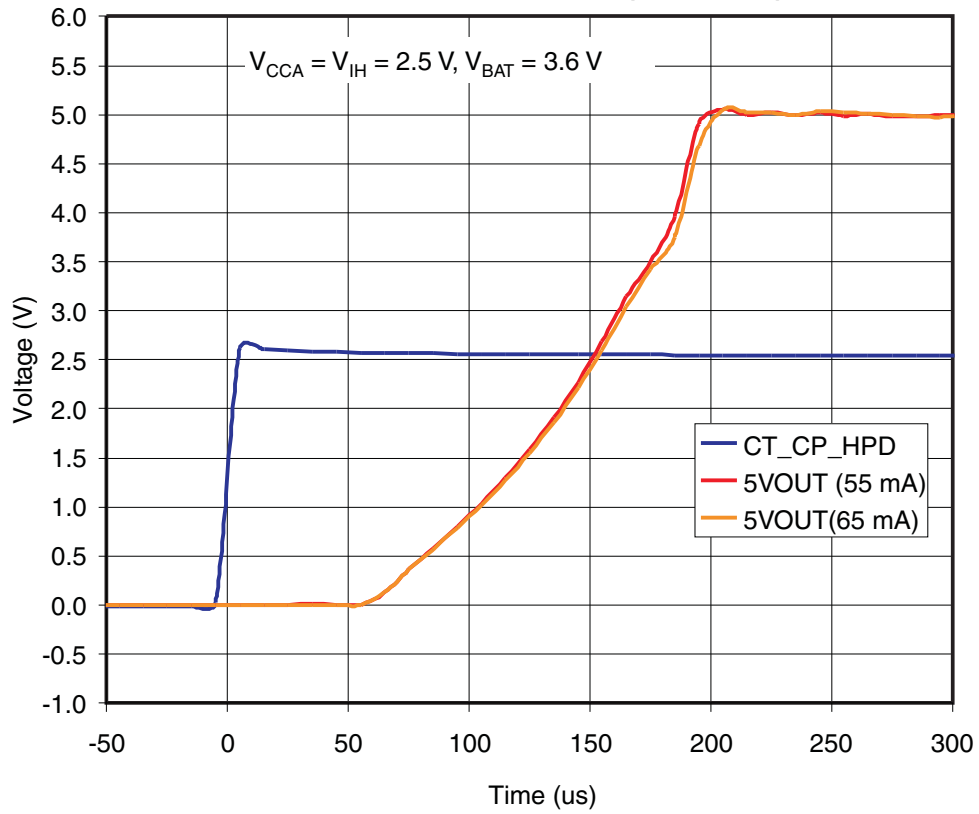


Figure 10. t_{START}

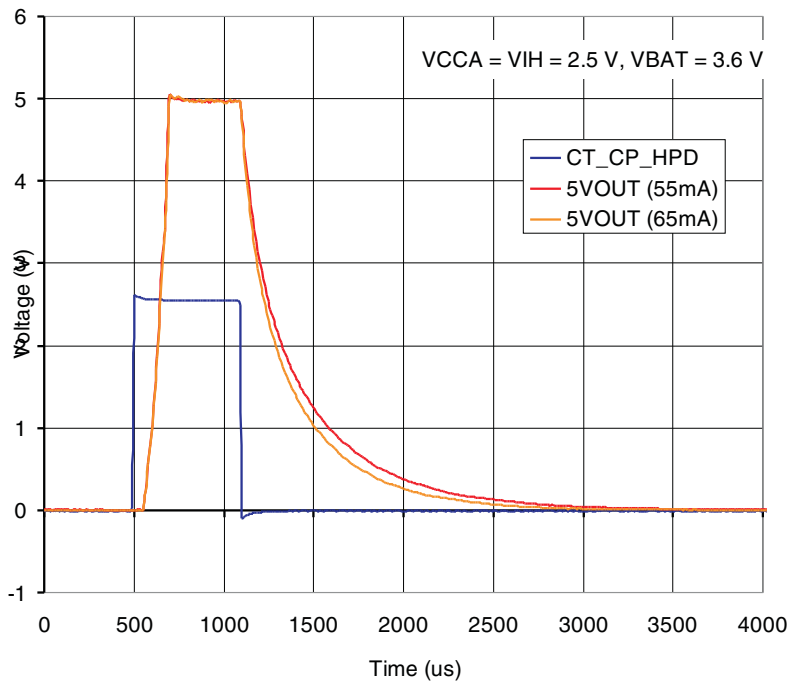


Figure 11. DC/DC Startup and Shutdown

TYPICAL CHARACTERISTICS (continued)

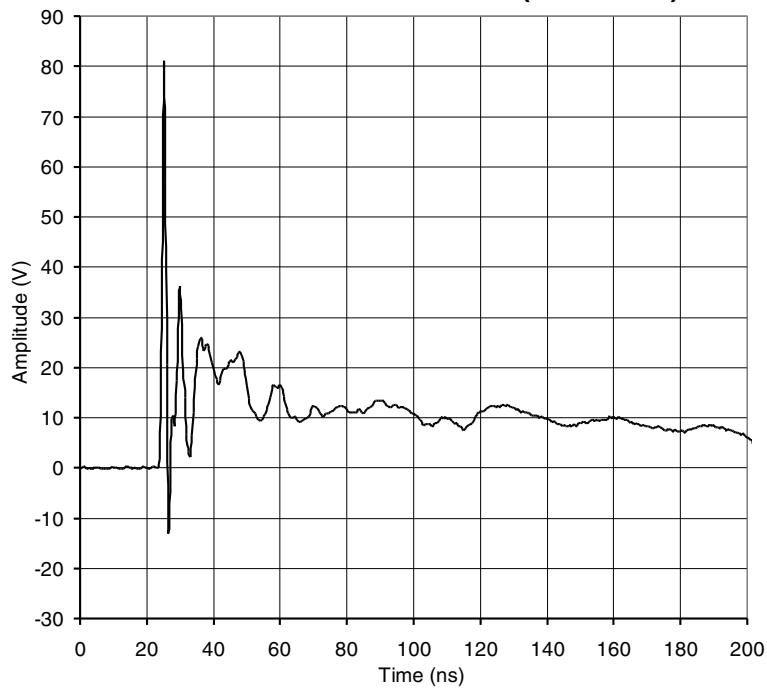


Figure 12. IEC Clamping Waveforms 8 kV Contact (IEC ESD Pins)

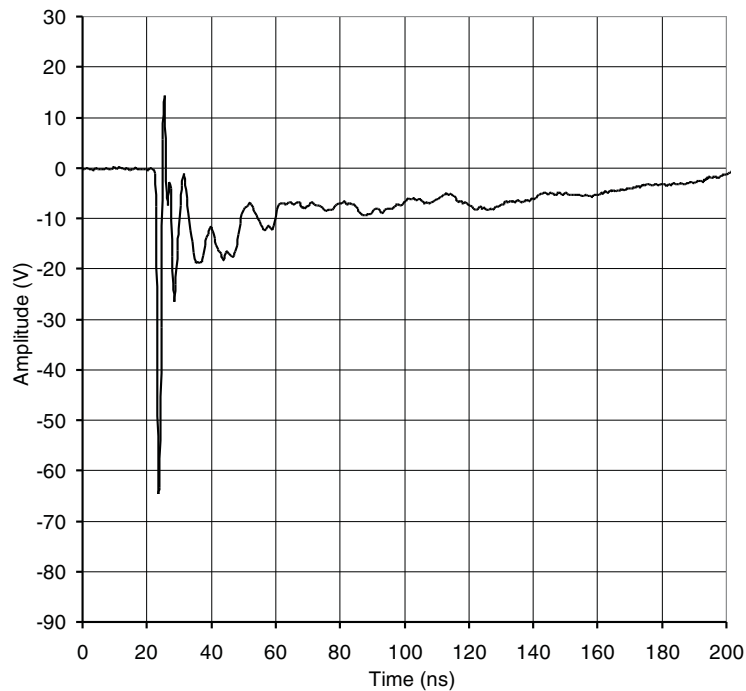


Figure 13. IEC Clamping Waveforms -8 kV Contact (IEC ESD Pins)

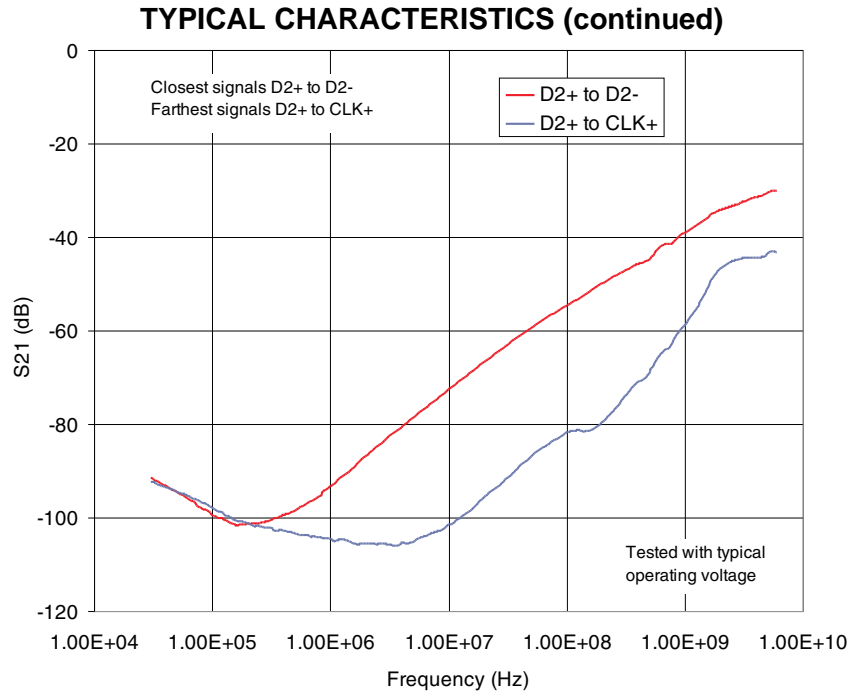


Figure 14. Channel-to-Channel Crosstalk

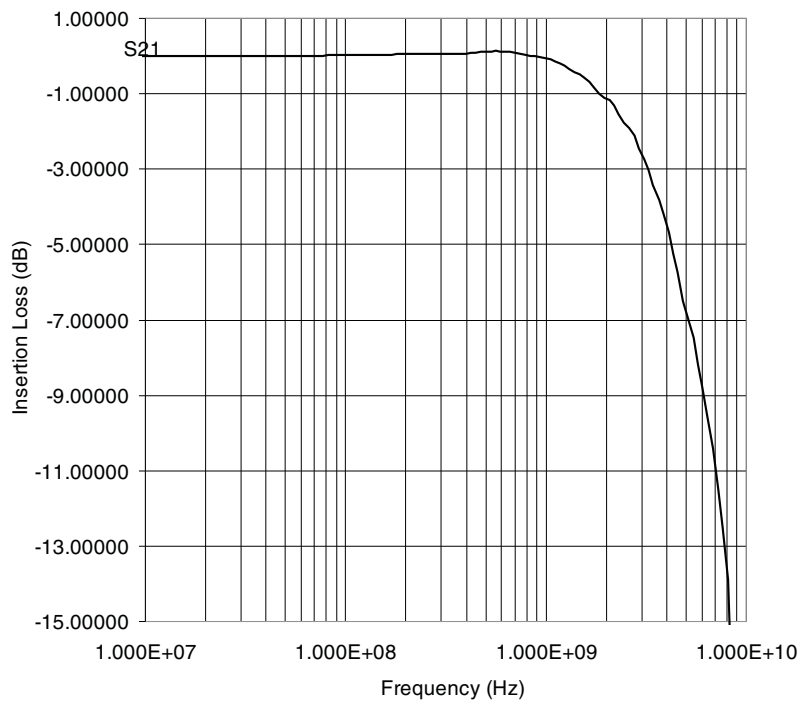


Figure 15. Insertion Loss Data Line to GND

TYPICAL CHARACTERISTICS (continued)

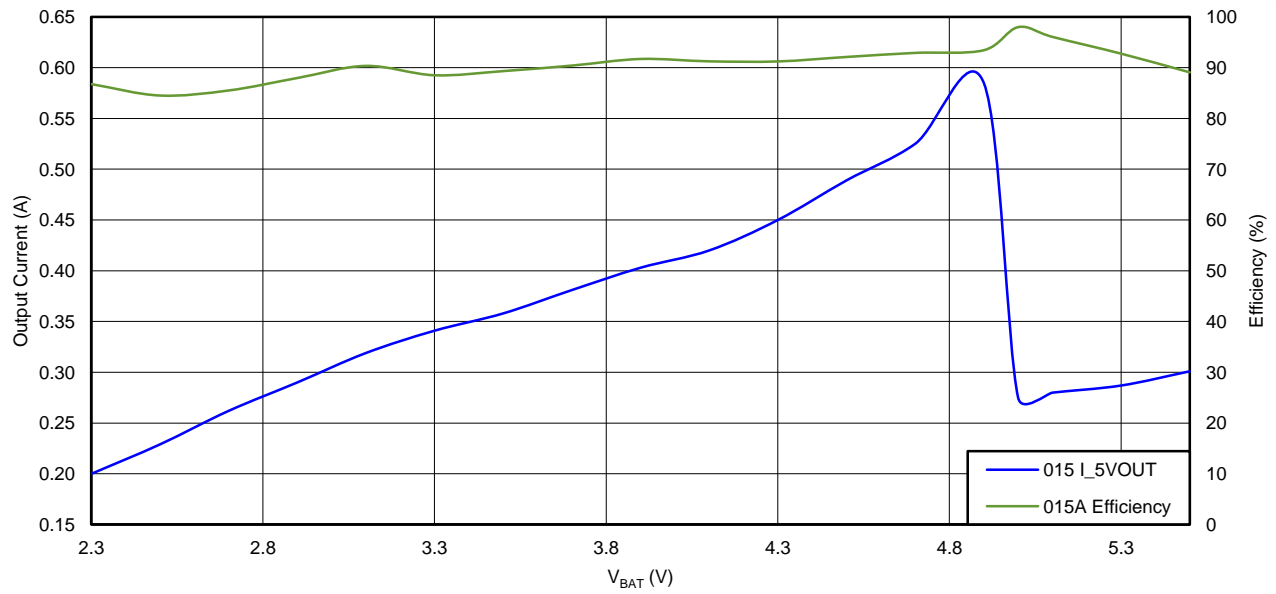


Figure 16. Power Derating Curve

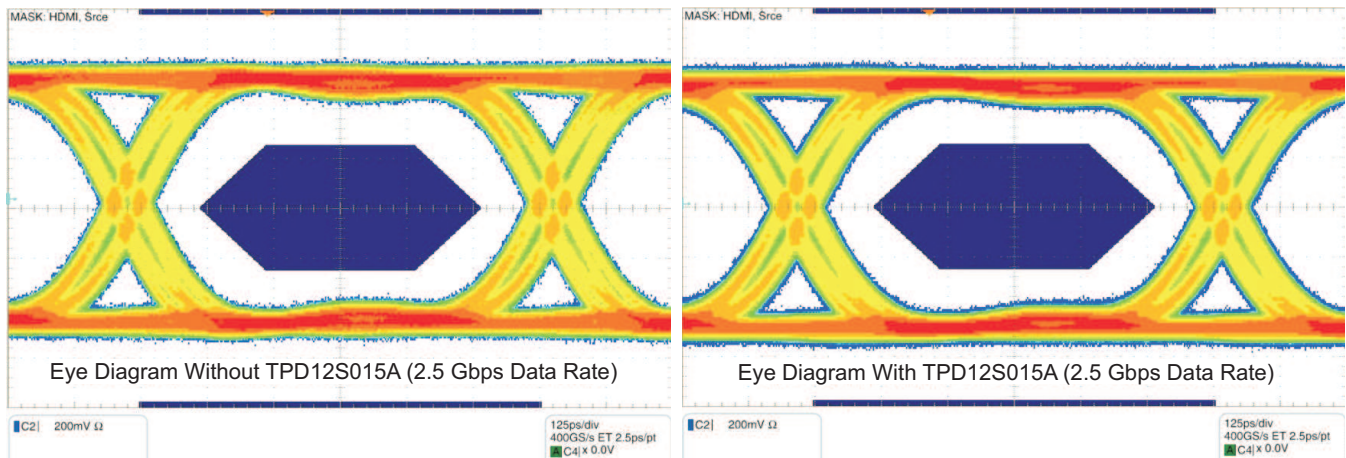


Figure 17. Eye Diagram Performance on a Test Board for the D+, D- Lines at 2.5 Gbps

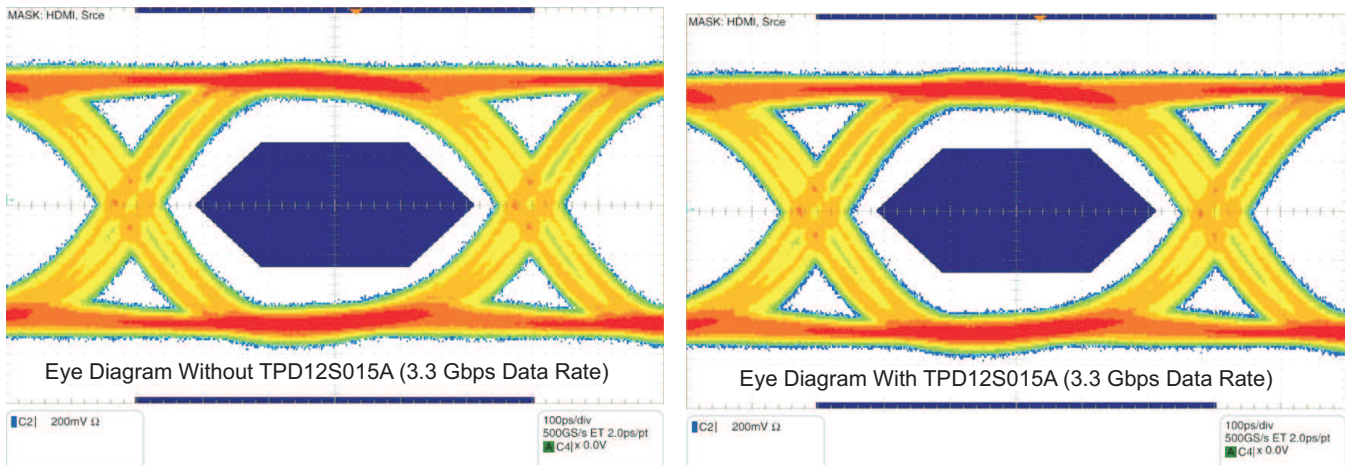
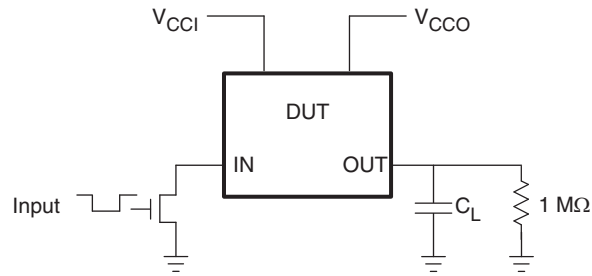
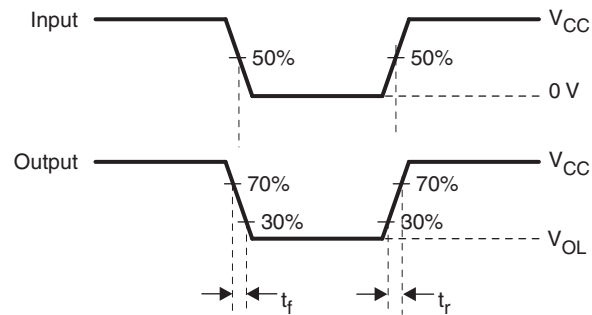


Figure 18. Eye Diagram Performance on a Test Board for the D+, D- Lines at 3.3 Gbps

PARAMETER MEASUREMENT INFORMATION



| PIN | CL |
|------------------------|--------|
| DDC, CEC (A side) | 750 pF |
| DDC, CEC, HPD (B side) | 15 pF |



- A. R_T termination resistance should be equal to Z_{OUT} of pulse generators.
- B. C_L includes probe and jig capacitance.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, slew rate ≥ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 19. Test Circuit and Voltage Waveforms

REVISION HISTORY

| Changes from Revision B (April 2012) to Revision C | Page |
|---|--------------------|
| • Changed Board Layout section | 20 |
| • Added Power Derating Curve | 26 |

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Top-Side Markings (4) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|------------------|----------------------|--------------|--------------------------|---------|
| TPD12S015AYFFR | ACTIVE | DSBGA | YFF | 28 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | PN015A | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

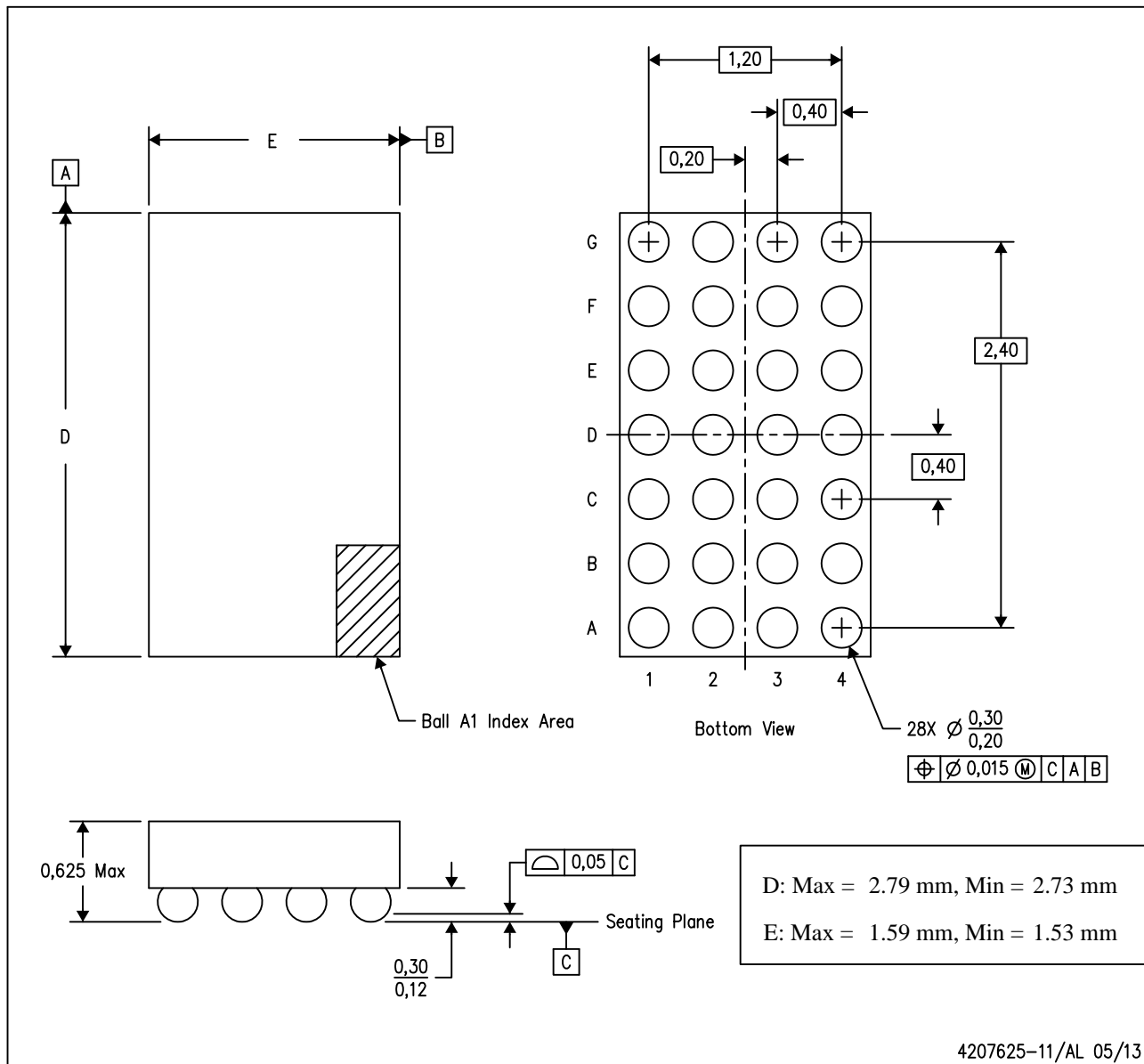
(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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YFF (R-XBGA-N28)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

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